

Temperature and Frequency Dependence of the Surface Resistance in the Vortex State of Type-II Superconductors

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The temperature and frequency dependence of surface-resistance data obtained in the vortex state of superconducting Pb-In alloys are analyzed. Measurements near H_{c2} indicate the normalized slope $s_2^{\frac{1}{2}} = (H_{c2}/R_n) \partial R / \partial H|_H$ tends to go to zero as the critical temperature is approached. The data are accounted for qualitatively if the frequency dependence of the flux-flow conductivity (dynamical fluctuations) is retained in the expression for the microwave current. There is no exact quantitative agreement, and the possibility of a strong-coupling correction is suggested.

In a recent paper,¹ henceforth to be called I, we made a comparison between experimental surface-resistance measurements near H_{c2} in type-II superconductors and the microscopic flux-flow theory.² At low temperatures the agreement between theory and experiments was excellent, and the $\kappa_2(t)$ parameter deduced from the surface-resistance measurements agreed with magnetization data obtained from the same samples.³ Near T_c , however, systematic deviations were observed and attributed to dynamical fluctuations of the vortex structure. These fluctuations are contained in our flux-flow expression for the conductivity $\sigma_s(H, \omega)$, and if we retain the frequency dependence of σ_s in the calculation of the surface resistance $R(H, \omega)$, we can account for the deviations observed. It is the purpose of the present note to examine this claim in some detail.

For the microwave current \vec{j}_ω we found in I [Eq. (11)]

$$\vec{j}_\omega = \left\{ -i\omega\sigma - \frac{2e^2\tau N}{m} \left[\Psi\left(\frac{1}{2} + \frac{i\omega}{2\pi T} + \rho\right) - \Psi\left(\frac{1}{2} + \rho\right) \right] \frac{|\Delta(\vec{r}, t)|^2}{2\epsilon_0(t) + i\omega} \right\} \vec{A}_\omega. \quad (1)$$

If we derive the conductivity $\sigma_s(H, \omega)$ as in I but keeping terms in $\omega/\epsilon_0(t)$, we find

$$\sigma_s(H, \omega) = \sigma - \frac{\langle M \rangle}{DH} \frac{1}{1 + ix}, \quad (2)$$

where $x = \omega/2\epsilon_0(t)$. An expression for the surface impedance Z near H_{c2} can then be derived as in I,

and from it we calculate the normalized slope $s_2^{\frac{1}{2}}(t, \omega)$, finding

$$s_2^{\frac{1}{2}}(t, \omega) = s_2^{\frac{1}{2}}(t, 0) \frac{1 + x(t)}{1 + x^2(t)}. \quad (3)$$

$s_2^{\frac{1}{2}}(t, 0)$ was found in I and for our samples reduces to

$$s_2^{\frac{1}{2}}(t, 0) \approx 0.862 [\kappa_2(0)/\kappa_2(t)]^2. \quad (4)$$

The factor $f(x) = (1+x)/(1+x^2)$ describes the extra absorption arising from the dynamical fluctuations and has its most pronounced effect near T_c . In that region

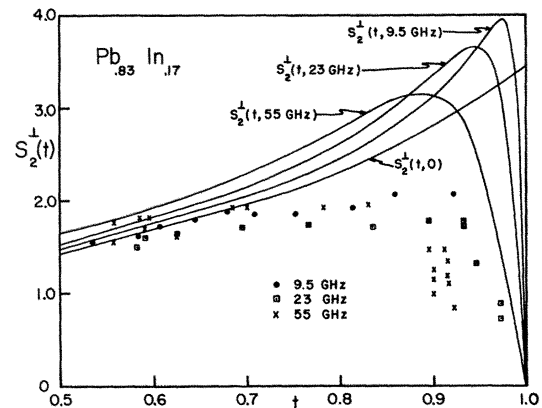


FIG. 1. Normalized slope $s_2^{\frac{1}{2}}(t)$ at H_{c2} of the surface resistance of a $\text{Pb}_{0.83}\text{In}_{0.17}$ alloy at frequencies of 9.5, 23, and 55 GHz. The curves are calculated as per Eqs. (3) and (4) of the text.

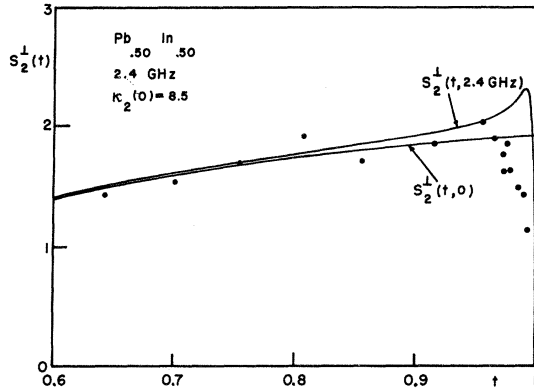


FIG. 2. Same as Fig. 1 for a $\text{Pb}_{0.50}\text{In}_{0.50}$ alloy at 2.4 GHz.

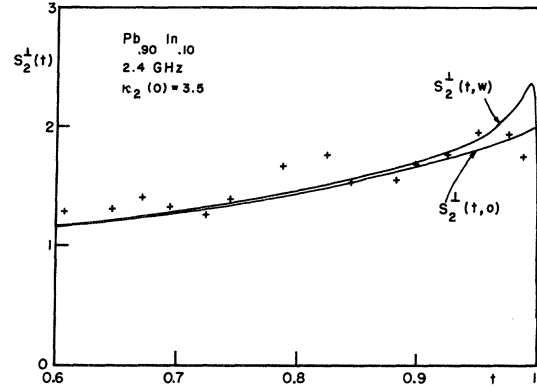


FIG. 3. Same as Fig. 1 for a $\text{Pb}_{0.90}\text{In}_{0.10}$ alloy at 2.4 GHz.

$$s_2^1(t, \omega) \Big|_{t \rightarrow 1} \rightarrow s_0^1(t, 0) \frac{2\epsilon_0(t)}{\omega} \rightarrow 0. \quad (5)$$

At low temperatures, $s_2^1(t, \omega) \rightarrow s_2^1(t, 0)$, which gives excellent agreement with experiments as reported in I.

Figures 1–3 show the calculated and measured slopes $s_2^1(t, \omega)$ for our samples.⁴ The agreement is qualitatively good; but the measured data do not have the peak corresponding to the region $0 < x < 1$, where $f(x) > 1$. In that region our theory predicts that the combined absorptions by flux-flow and fluctuations should be less than the absorption arising from flux-flow alone. This feature cannot be concluded from the experimental data. The increase in absorption [corresponding to a decrease of $s_2^1(t, \omega)$ in our figures] and its

frequency dependence, however, are quite well reproduced when $x > 1$. At present we do not know what prevents a better agreement between experiments and theory except to suggest that this may be a strong coupling effect, such that $x = \omega/2\epsilon_0(t)$ may have to be replaced by $x^* = \omega/2\epsilon_0^*(t)$, the asterisk indicating a renormalized quantity. With a ratio $\epsilon_0^*/\epsilon_0 = 2.2$ the agreement between measured and calculated $s_2^1(t)$ is very noticeably improved. This can be seen in Fig. 1 by comparing the experimental data at 23 GHz with the calculated curves at 23 and 55 GHz.

In conclusion, we have seen that the microscopic theory of flux-flow explains the observed surface resistance very well at low temperature and that the dynamical fluctuations give a qualitative fit to the observed behavior near T_c .

⁴G. Fischer, R. D. McConnell, P. Monceau, and K. Maki, Phys. Rev. B **1**, 2134 (1970).

²This theory is given in Ref. 1, together with full references to earlier work on flux-flow theory.

³J. le G. Gilchrist and P. Monceau, J. Phys. C **3**, 1399 (1970).

⁴The experimental data presented in this paper are the same as in I. We should like to acknowledge again that the 23- and 55-GHz data have been supplied by Dr. B. Rosenblum, Dr. J. I. Gittleman, and Dr. A. Rothwarf of the RCA Laboratories, Princeton, N. J.